

Docket No.: 8733.307.00-US

(PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:

Oh-Nam Kwon

Application No.: 09/709,483

Filed: November 13, 2000

For: METHOD OF MANUFACTURING A THIN

FILM TRANSISTOR

Group Art Unit: 2823

Examiner: Pham, Thanh, V.

AMENDMENT

Box Non-Fee Amendment Commissioner for Patents Washington, DC 20231

Dear Sir:

In response to the Office Action dated November 5, 2002, please amend the aboveidentified U.S. patent application as follows:

In the Claims

Please amend the claims as follows (A marked-up version of the amended claims is attached):

1. (Amended) A method of manufacturing a thin film transistor for use in an LCD device, comprising:

preparing a glass substrate and a mixed solution, the mixed solution having a reductant and a first metal;

forming a photoresist pattern on the glass substrate;

etching a portion of the glass substrate to form a groove beneath a top surface of the glass substrate using the photoresist pattern as a mask;

DC:113697.1